



U-2900/2910

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# General guide for answering inquiries: 7 questions

Choose model by: I. Specification II. Application





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- 1. Wavelength range?
- 2. What type of beam?
- 3. Bandpass necessary?
- 4. Xenon or D2/W lamp?
  - 5. Detector type?
- 6. Liquid or solid sample?
- 7. If liquid, temperature control?

Or if solid, Reflectance/Transmittance/Absorbance?

## I. Choose UV spectro according to specifications



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## **II.** Choose UV spectro according to applications



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# Guide for answering inquiries: 7 questions Choose model by: I. Specification II. Application

## I. Choose UV spectro according to specifications



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# 1. Wavelength range

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# 2. Beam: Single beam and double methods



The intensity of the light source is not stable, but oscillates due to changes in temperature, humidity, wind patterns, and so on.

By taking the ratio of the intensity of a sample to that of a control, the oscillation can be corrected (the baseline becomes stable, after a time).

For long-time, continuous measurements or enzyme activity measurements, the double beam method is highly recommended!



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Sample side

1.000 0.998 0.996 0.994 0.992 Sample: JQA Filter 0.004 0.002 Sample:None 0.000 -0.002 -0.004 0 1000 3000 4000 2000 Time / s

Time

Intensity

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Intensity

## 2. Hitachi Ratio and Double beam

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#### Comparable with single beam

## 3. Spectral bandwidth (bandpass)



### The spectral bandwidth is related to the physical slit width.

In general, reducing the physical slit width decreases the spectral bandwidth and improves the resolution (ability of the instrument to resolve close peaks). However, it decreases the energy reaching the sample, which might increase noise levels.



# 4. Light source

Kind	Incandescent lamp Tungsten	Deuterium discharge lamp	Flash Xenon lamp
Symbol	W, WI	D <sub>2</sub>	Хе
Characteristic	Emitting continuous spectrum of 300-3000nm	Emitting continuous spectrum of 168-500nm with energy peak at 250nm	Emitting continuous spectrum of 200 nm- 1100 nm Long lifetime
Wavelength	340 <b>~</b> 1100 nm	185 <b>~</b> 360 nm	200 nm- 1100 nm
Energy			
	White color	Blue color for a formation of the format	$\begin{bmatrix} & Complete UV-Vis \\ range \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ $

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## **Types of detector**

### Photodiodes (photocells)

### Photomultiplier tube (photomultiplier)

### PbS (lead sulfide)



Cover the visible region. It is common for photocells to be made of cadmium sulfide and photovoltaic cells of silicon. It is small and also sensitive to light with a relatively short wavelength.



Side-on type photomultiplier

Equipped with phototubes sensitive to both the UV and visible regions, and multipliers that amplify roughly 107 times. The sensitivity can be broadly varied by increasing the applied voltage.



Detector sensitive to the nearinfrared region

## **II.** Choose UV spectro according to applications



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## 6. Solid samples



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## 6. Solid samples

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### UH4150











#### Micro cell holder (P/N 122-0060) Suitable for measurement of trace samples in medical and biochemical fields. Specifications (cell required separately) Wavelength range 220 to 950 nm Cell mounting Within ±0.3%T /demounting repeatability Within ±0.005 Abs Raseline flatness (50 mL micro-volume cell used) Mask for Micro cell To be inserted into a standard rectangular cell holder for measurement of a trace sample. Specifications 200-1537 Mask for Micro cell (1.5 mm) 200-1538 Mask for Micro cell (1.2 mm) Cell 124-0357 Micro guartz cell, 10 mm 200-0551 Black quartz micro cell, 10 mm

The following cells are usable for the above micro cell holder (P/N 122-0060).





#### Ultra-micro volume sample measurement

Ultra-micro volume cells are used in the sample chamber of the UH5300 in combination with the holder base (3J1-0109), single cell holder (3J1-0106), and trace sample cell mask (3J1-0116). It is suited for the measurement of a trace sample of about 1.5 to 90  $\mu L.$ 

Product name	P/N	Capacity (µL)	Light path length nam
1.5 µL trace sample cell	3J2-0120	1.5 to 4.0 µL	1 mm
12 µL trace sample cell	3J2-0121	12 to 40 µL	5 mm
50 µL trace sample cell	3J2-0122	50 to 90 µL	10 mm
Mask for trace sample cell	3J1-0116	-	-

U-5100



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#### Micro cell

Micro cells are used in the sample chamber of the UH5300 in combination with the holder base (3J1-0109), single cell holder (3J1-0106), and micro cell mask (200-1537). It is suited for the measurement of a small amount of sample of about 340 to 600 µL.

	Product name	P/N	Capacity (µL)	Light path length
	Micro quartz cell, 10 mm	124-0357	240 to 600 ul	10 mm
	Black quartz micro cell, 10 mm	200-0551	340 to 600 µL	TOTIM
	Mask for micro cell	200-1537	_	_
H5300		UH5700		

Uses regular 10 mm single cell holder. Easier to use

Requires holder accessory. Cell manipulation is not so easy.



### Cylindrical long path cell holder



(6 positions is standard for U-5100 and UH5300)

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### Auto sipper

U-5100

UH5300

5.

Auto sipper (P/N 3J2-0105) The automatic sipper takes a sample from a test tube and can automatically measure it.

Minimum sample volume	0.6 mL
Carryover	1% maximum
Cell size	Approx. 50 µL



#### Auto sipper (P/N 3J1-0101)

Effective for quick measurement of multiple samples. When the lever is depressed, the automatic sipper takes a sample from a test tube and measures it automatically.

Minimum sample volume	0.6 mL
Carry over	1 % or less
Cell capacity	Approximately 50 µL

### Auto sipper

#### Different P/N for each model

This computer-controlled sample sipper is provided with a sample recovery function and other versatile functions. In combination with an autosampler, this unit will further advance automation and labor saving in the preparatory stage. This sipper cannot control temperature.



#### Specifications

Minimum sample volume	0.6 mL
Carryover	1% or less
Cell capacity	About 50 µL
Optical path length	10 mm
Reference beam side	10 mm rectangular cell mountable

### 0/2910 U-3900/3900H UH5700





### Require circulatory water bath:



### Temperature of the water bath:



#### Water circulated cell holder with stirrers Different P/N for each model

A magnetic stirrer agitates the sample solution, allowing measurement with high temperature accuracy. Using Starna's magnetic stirred micro cells allows for measuring a small amount of sample

Operati	ng temperature rang	9	5 °C to 60 °C
C	ompatible cells		Capacity
10	mm square cell		2.4 to 3.5 mL
Starna's	9-Q-10-MS, 29-Q-1	0-MS	1.0 to 1.5 mL
stirring cell	18-Q-10-MS, 28-Q-	-10-MS	600 to 800 µL
	UH5300	U	H5700

### Water circulated cell holder (P/N 210-2111)

Water from a thermostatic chamber is circulated through this cell holder to maintain a sample cell at a constant temperature.



Specifications (circulating thermostatic chamber and cell not included in this product) Operating temperature range From normal temperature to 40°C Temperature stability Within ±0.3°C

# U-2900/2910 U-3900/3900H UH5700

Temperature regulated by thermostat, circulating water for cooling (circulating tap water OK)



Electronic thermostatted cell holder (P/N 131-0301 for 115 V) (P/N 131-0302 for 200 V)

Electronically controlled constant-temperature cell holder using a Peltier device. This accessory requires front panel (P/N: 3J1-3214). Place an order separately.



#### 6-cell positioner with temperature control (P/N 2J1-0103/0104)

Six 10 mm cells can be mounted on the sample beam side, and they can be changed over automatically at certain intervals. (Temperature control : S only)

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#### Specifications

Repeatability in cell changeover	Within ±0.5 % (at 100 %T)
Applicable cell	10 mm cell (not included in this unit)
Setting temperature	20 to 40 °C

\*: Not including circulatory thermostatic oven and cell

#### U-2900/2910



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### More details:

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### "Sales information", Manual

Sales Information

Sales Information

Compariso

Table 1-2 compares the U-2900 with our U-2800A

Table 1-2 Cor

	Hita	chi	Hitachi U-2800A
Model	U-2	900	Double beam
Optical system Display	Doubl Color (680 10.4	e beam LCD × 480) inch	LCD (680 × 480) O
Wavelength range Stray light	Tilt (*) 191 11 W	0 to 00 nm ithin 0.05%	190 to 1100 nm Within C
Spectral bandwidth accuracy Wavelength repetability Baseline fal Baseline fal Baseline fal Onfth Noise leve Scan spe	setting mess ability I ed	1.5 nm ±0.3 nm(05 488.0nm) ±0.1 nm ±0.002 Al 0.0003 A 0 0.0003 0 10, 101 800, 1 3800 r	1.5r 8.1. ±0 
Measur mode	ement	Phot Wav Tim Mul me No	ometn eleng' e scar ti-wav asure ne

Specifications of U-2900         of       Image: Seys-Namioka mount, Double beam         of       Seys-Namioka mount, Double beam         of       Seys-Namioka mount, Double beam         Spectral bandwidth       1.0 to 1100 nm         Spectral bandwidth       1.5 nm         Stray light       Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )         Wavelength setting       ±0.1 nm         Stray light       Within 0.05% (220nm Nal, 540nm NaNO <sub>2</sub> )         Wavelength setting       ±0.1 nm         Photometric accuracy       ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (1.5 to 1.0 Abs) ±0.004 Abs (1.5 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs)         Photometric repeatability       ±0.001 Abs (0 to 0.5 Abs) ±0.004 Abs (1.0 to 2.0 Abs)         Wavelength scan speed       10.100, 200, 400, 800, 1200, 2400, 3000 nm/mini ±0.1987         Wavelength scan speed       10.100, 200, 400, 800, 1200, 2400, 3000 nm/mini ±0.1987         Wavelength scan speed       10.00015 Abs (200 to 80 nm)         Baseline stability (Dritt)       0.0003 Abs/tr (500 nm)         Baseline stability (Dritt)       0.0000 Abs (200 to 80 nm)         Wavelength scan speed       10.100, 200 abs (1.000 sc 00 nm)         Baseline stability (Dritt)       0.0003 Abs/tr (500 nm)         Baseline stability (Dritt)       0.0000 Abs (200 to 80 nm)         Ught source	Image: Second	f			Model U-2900 s
of     Item     Specification       Optical system     Seya-Namicka mount. Double beam       At     Optical system     Seya-Namicka mount. Double beam       Spectral bandwidth     1.5 nm       Stray light     Wavelength ange       Stray light     With 0.05% (220nm Nal. \$40nm NaNO <sub>2</sub> )       Wavelength accuracy     20.3 nm (656.1nm, 488.0nm)       Wavelength accuracy     20.3 nm (656.1nm, 488.0nm)       Wavelength accuracy     20.002 Abs (0 to 0.5 Abs)       Wavelength accuracy     20.002 Abs (0 to 0.5 Abs)       Wavelength accuracy     20.002 Abs (0 to 0.5 Abs)       Wavelength accuracy     20.004 Abs (0.5 to 1.0 Abs)       Photometric accuracy     20.004 Abs (0.5 to 1.0 Abs)       With NIST SRM 930 filter)     20.004 Abs (0.5 to 1.0 Abs)       Workelingth scan speed     10.100,200,400.800,1200,2400,3000 nm/mini       Baseline stability (Drift)     0.0003 Abs/t (500 nm)       Baseline stability (Drift)     0.0003 Abs/t (500 abs 00 nm)       Light source     Witamp. D, lamp       Light source switching     Xuitcontic (user srelectable from 325 to 370nm)       Display     Color LCD with back-light (10.4 inch)	Image: consumptionSpecificationSpecial systemSeya-Namioka mount. Double beamVavelength range160 to 1100 nmSpectral bandwidth1.5 nmSpectral bandwidth1.5 nmSpectral bandwidth1.5 nmSpectral bandwidth1.5 nmSpectral bandwidth1.5 nmSpectral bandwidth1.5 nmSpectral bandwidth1.0 nmSpectral bandwidth1.0 nmSpectral bandwidth2.0 1 nmWavelength securacy1.0 002 Abs (0 to 0.5 Abs)Wavelength securacy1.0 002 Abs (0 to 0.5 Abs)10.004 Abs (1.0 to 2.0 Abs)20.001 Abs (0 to 0.5 Abs)20.001 Abs (0 to 0.5 Abs)20.002 Abs (0 5 to 1.0 Abs)20.002 Abs (0 5 to 1.0 Abs)20.004 Abs (0.5 to 1.0 Abs)20.004 Abs (0.00 Abs (0.00 m)Mavelength scan speed10.100, 200, 400, 800, 1200, 2400, 3800 nm/minBaseline stability (Drift)Do003 Abs/m (500 nm, 2 hours after power on)Noise level20.0004 Abs (200 to 860 nm)Light source switchingAutomatic (user selectable from 325 to 370m)Silicon photododeSilicon photododeSilicon photododeSilicon photododeSilicon photododeSilic			Specifications of U.o.	
Item         Specification           Optical system         Seya-Namioka mount, Double beam           Wavelength range         190 to 1100 nm           Spectral bandwidth         1.5 nm           Stray light         Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )           Wavelength acouracy         ±0.3 nm (680, 1nm, 480, 0nm)           Wavelength acouracy         ±0.3 nm (680, 1nm, 480, 0nm)           Wavelength acouracy         ±0.3 nm (680, 1nm, 480, 0nm)           Wavelength acouracy         ±0.002 Abs (0 to 0.5 Abs)           Wavelength acouracy         ±0.004 Abs (0, to 1.0 Abs)           With NIST SRM 080 filler)         ±0.004 Abs (0, to 1.0 Abs)           Wowelength scan speed         10, 100, 200, 400, 800, 1200, 2400, 3800 nm/min           Response         FAts. Medium, 510w           Baseline stability (Drift)         0.00016 Abs (200 to 960 nm)           Light source         Witamp, D, lamp           Light source         Witamp, D, lamp           Light source         Witamp, D, lamp           Detector         Silicon photodiode	ItemSpecificationOptical systemSeya-Namioka mount, Double beamWavelength range190 to 1100 nmSpecifi Bandwidth1.5 nmStray lightUto 10 (0.5% (220nm Nal, 340nm NaNO <sub>2</sub> )Wavelength acouracy20.3 nm (056 1rm, 486.0nm)Wavelength setting20.1 nmPhotometric acouracy±0.002 Abs (0 to 0.5 Abs)(with NIST SRM 930 filter)±0.002 Abs (0 to 0.5 Abs)20.01 Abs±0.02 Abs (0 to 0.5 Abs)20.01 Abs±0.004 Abs (0.5 to 1.0 Abs)20.01 Abs±0.004 AbsWeth NIST SRM 930 filter)±0.004 Abs20.02 Abs0.5 to 1.0 Abs)20.01 Abs±0.004 Abs20.004 Abs(20.01 to 820 nm)20.004 Abs0.000 4AbsBaseline stability (Drift)0.0003 Abs/m (500 nm, 2 hours after power on)Noise level±0.0004 Abs (200 to 890 mm)Light source switchingAutomatic (user seleclable from 325 to 370m)SteleoriSilicon photodoideWil amp, D, lampColor LCD with back-light (10.4 inch)sel Abs20.004 (JW) × 605(D) × 283(H) (LCD folded)sel AbsAutomatic (user seleclable from 325 to 370m)Silicon photodoideSilicon photodoideWil amp, D, lampAutomatic (user seleclable from 325 to 370m)Silicon photodoideSilicon photodoideSilicon photodoide<	ot			900
Optical system         Sepectification           Viavelength range         190 to 1100 nm           Spectral bandwidth         1.5 nm           Spectral bandwidth         1.5 nm           Stay light         Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )           Wavelength accuracy         ±0.3 nm (d56.1 nm, 488.0 nm)           Photometric accuracy         ±0.3 nm (d56.1 nm, 488.0 nm)           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Drift)         ±0.00013 Abs/t (200 nm, 2 hours after power on)           Baseline flatness         ±0.00013 Abs (200 to 66 nm)           Light source         W100013 Abs (10 obe 2.0 400, 3800 nm/min           Light source         W100013 Abs (200 to 66 nm)           Light source         W100013 Abs (200 to 66 nm)           Light source         W100015 Abs (200 to 800 s1070m)           Light source         W100015 Abs (200 to 861 nm 325 to 370nm)           Display         Coler LCD with back-light (10 4 inch)	Optical system         Sepecification           Wavelength range         160 to 1100 nm           Spectral bandwidth         1.5 nm           Stay light         Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )           Wavelength accuracy         20.3 nm (656.1nm, 488.0nm)           Wavelength setting         20.1 nm           Photometric accuracy         20.3 nm (656.1nm, 488.0nm)           Wavelength setting         20.1 nm           Photometric accuracy         20.3 nm (55.5 to 1.0 Asis) ±0.004 Abs (0.5 to 1.0 Asis) ±0.004 Abs (0.5 to 1.0 Asis) ±0.008 Abs (1.0 to 2.0 Abs) ±0.009 Abs (1.0 to 2.0 Abs)           Photometric accuracy         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs           Wavelength scan speed         10.100.200.400.800.1200,2400.3800 nm/min           Response         Fast, Medium, Slow           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Baseline stability (Drift)         0.0003 Abs/hr (500 nm)           Upit source switching         Automatic (user selectable from 325 to 370nm)           itsils revel         20.00015 Abs (8001)           upit source switching         Automatic (user selectable from 326 to 370nm)           itsilson photodiode         mit UF           revel         50.00(M) × 805(D) × 283(H) (LCD foldied)	Item			
Main         Seys-Namioka mount, Double beam           Spectral bandwidth         1.90 to 1100 nm           Spectral bandwidth         1.8 nm           Stray light         Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )           Wavelength accuracy         ±0.3 nm (656.1 nm, 486.0nm)           Wavelength setting         ±0.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs)           Wavelength setting         ±0.002 Abs (0 to 0.5 Abs)           Work in NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs)           Work in NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs)           Wavelength setting         ±0.000 Abs (0.5 to 1.0 Abs)           With NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs)           Wavelength setting         ±0.002 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (0.5 to 1.0 Abs)         ±0.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.100, 200, 400.800, 1200, 2400, 3800 nm/minin           Response         Fast, Medium, Slow           Baseline stability (Drift)         0.0003 Abs/17 500 nm, 2 hours after power on)           Baseline stability (Drift)         0.0003 Abs/17 500 nm, 2 hours after power on)           Uight source         Wi lamp, D, lamp           Uight source switching         Automatic (user selectable from 325 to 370nm)	Wavelength range       Seya-Namioka mount. Double beam         Spectral bandwidth       150 to 1100 nm         Stray light       Within 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )         Wavelength accuracy       20.3 nm (656.1nm, 486.0nm)         Wavelength accuracy       1.0.1 nm         Photometric accuracy       1.0.072 Abs (0 to 0.5 Abs)         (with NIST SRM 030 filter)       ±0.002 Abs (10 to 0.5 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)       ±0.002 Abs (1.0 to 2.0 Abs)         (with NIST SRM 030 filter)       ±0.001 Abs (0 to 0.5 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)       ±0.004 Abs (1.0 to 2.0 Abs)         (with NIST SRM 030 filter)       ±0.001 Abs (0 to 0.5 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)       ±0.004 Abs (1.0 to 2.0 Abs)         Wavelength scart speed       10.100, 200, 400, 800, 1200, 2400, 3600 nm/min         Baseline stability (Drift)       0.0003 Abs/hr (500 nm, 2 hours after power on)         Noise level       ±0.00015 Abs (000m)         Light source switching       Automatic (user selectable from 326 to 370nm)         stillor protocil stability       Color LCD with back-light (10.4 inch)         tript       Calor LCD with back-light (10.4 inch)         tript       Cantronics         wital UF       Color LCD with back-light (10.4 inch)         tript       Cantronic	Optical system		Specification	
Spectral bandwidth         190 to 1100 nm           Stray light         1.5 nm           Stray light         Winin 0.05% (220nm Nal, 340nm NaNO <sub>2</sub> )           Wavelength acouracy         ±0.3 nm (868.1 nm, 488.0 nm)           Wavelength acouracy         ±0.3 nm (868.1 nm, 488.0 nm)           Wavelength acouracy         ±0.1 nm           Photometric acouracy         ±0.002 Abs (0 to 0.5 Abs)           20.002 Abs (0 to 0.5 Abs)         ±0.004 Abs (0.5 to 1.0 Abs)           With NIST SRM 930 filter)         ±0.001 Abs (0 to 0.5 Abs)           Workeingth setting         ±0.0002 Abs (0 to 0.5 Abs)           Workeingth setting         ±0.0002 Abs (0 to 0.5 Abs)           Workeingth setting         ±0.0002 Abs (0 to 0.5 Abs)           Workeingth scan speed         10.1 to 2.0 Abs           Noise level         ±0.0002 Abs (1.0 to 2.0 Abs)           Baseline stability (Drift)         0.0003 Abs/(500 nm)           Light source         ±0.00016 Abs (500 hm)           Light source switching         Wi lamp, D; lamp           Uetcolor         Silicon photocloide           Display         Color LCD with back-light (10.4 inch)	Spectral bandwidth         150 to 1100 nm           Stary light         1.5 nm           Stary light         1.5 nm           Wavelength accuracy         20.3 nm (866, 1nm, 480, 0nm)           Wavelength setting         20.1 nm           Photometric accuracy         20.3 nm (866, 1nm, 480, 0nm)           Photometric accuracy         20.1 nm           Photometric accuracy         20.02 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.5 to 1.0 Abs) ±0.003 Abs (1.5 to 1.0 Abs) ±0.002 Abs (1.5 to 1.0 Abs)           Photometric repeatability         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (1.5 to 1.0 Abs) ±0.002 Abs (1.5 to 1.0 Abs)           Wavelength scan speed         10.002 Abs (0.5 to 1.0 Abs) ±0.003 Abs (1.0 to 2.0 Abs ±0.003 Abs (1.0 to 2.0 Abs ±0.004 Abs (1.0 to 2.0 Abs ±0.004 Abs (1.0 to 2.0 Abs ±0.004 Abs (1.0 to 2.0 Abs ±0.0001 Abs (0.5 to 1.0 Abs)           Baseline stability (Dnft)         D.0003 Abs/m (500 nm, 2 hours after power on)           Noise level         ±0.0001 5 Abs (500 nm)           Light source         Wi lamp. D <sub>2</sub> lamp           Variet stability (Dnft)         D.0003 Abs/m (500 nm, 2 hours after power on)           Noise level         ±0.0001 5 Abs (500 nm)           Light source         Wi lamp. D <sub>2</sub> lamp           Vity         Color LCD with back-light (10.4 inch)           tial UP         Centronics           setory	Wavelength range		Seya-Namioka mount Double L	
Stray light         1.5 nm           Wavelength accuracy         Within 0.05% (200m Nal. 340nm NaNO <sub>2</sub> )           Wavelength setting         ±0.3 nm (856.1nm, 486.0nm)           Wavelength setting         ±0.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           (with NIST SRM 830 fitter)         ±0.004 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           Photometric repeatability         ±0.001 Abs (0 to 0.5 Abs) ±0.004 Abs (0 to 0.5 Abs) ±0.004 Abs (0 to 0.2 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Drift)         ±0.0001 Abs (0 00 60 nm)           Noise level         ±0.0001 Abs (0 000 film)           Light source         Witim, S100 filer)           Light source         Witim S100 filer)           Dotod Abs (0 10 0.200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Drift)         0.0001 Abs (100 to 806 nm)           Display         ±0.00016 Abs (200 to 806 nm)           Light source         Witamp, D; lamp           Light source         Silicon photodolde           Display         Color LCD with back-sight (10.4 inch)	Stray light         1.5 nm           Wavelength acouracy         10.3 nm (858, 1nm, 488, 0nm)           Wavelength setting         20.1 nm           Photometric acouracy         1.0 007 Abs (0 to 0.5 Abs)           Yavelength setting         20.1 nm           Photometric acouracy         1.0 007 Abs (0 to 0.5 Abs)           Yavelength setting         20.1 nm           Photometric acouracy         1.0 007 Abs (0 to 0.5 Abs)           Yavelength setting         20.0 1 Abs (0 to 0.5 Abs)           Yavelength setting         20.0 1 Abs (0 to 0.5 Abs)           Yavelength setting         20.001 Abs (0 to 0.5 Abs)           Yavelength scan speed         10.002 Abs (0 to 0.5 Abs)           Yavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3000 nm/min           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         20.00015 Abs (200 to 860 nm)           Yaht source switching         Automatic (user selectable from 325 to 370m)           Yaht source switching         Automatic (user selectable from 325 to 370m)           Yaht source switching         Automatic (user selectable from 325 to 370m)           Yaht source switching         Automatic (user selectable from 325 to 370m)           Yaht source switching         Automatic (user selectable from 325 to 370m)	Spectral bandwidth		190 to 1100 nm	
Wavelength accuracy         ±0.3 nm (68.1 nm, 488.0 nm)           Wavelength setting         ±0.3 nm (68.1 nm, 488.0 nm)           repeatability         ±0.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs)           ±0.003 Abs (1.0 to 2.0 Abs)         ±0.003 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.102 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.102, 200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Drift)         0.0003 Abs/(1.0 to 2.0 Abs)           Baseline stability (Drift)         0.0003 Abs/(1.000 S00 nm)           Noise tevel         ±0.00015 Abs (0.5 0to 300 nm)           Light source         ±0.00015 Abs (0.000 m)           Uight source         ±0.00015 Abs (0.0000 m)           Light source         ±0.00015 Abs (0.0000 m)           Light source         ±0.00015 Abs (0.0000 m)           Light source         ±0.00015 Abs (0.0000 m)           Detector         Silicon photodiode           Display         Color LCD with back-sight (10.4 inch)	Wavelength accuracy         ±0.3 nm (650.1nm, 480.0nm)           Wavelength setting         ±0.1 nm           repeatability         ±0.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           Wavelength setting         ±0.017 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           Photometric accuracy         ±0.001 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3000 nm/min           Response         Fast, Medium, Slow           Baseline stability         0.0004 Abs (20 to 0.50 nm)           Ught source         ±0.0004 Abs (200 to 0.50 nm)           Ught source         ±0.0004 Abs (200 to 0.50 nm)           Ught source         ±0.0004 Abs (200 to 0.50 nm)           Ught source         Will imp, D <sub>b</sub> lamp           Noise level         ±0.0004 Abs (200 to 0.50 nm)           Ught source         Will imp, D <sub>b</sub> lamp           Valor photodiode         foor µLob with back-light (10.4 inch)           risplay         Color LCD with back-light (10.4 inch)           se         50.00W) × 005(D) × 283(H) (LCD folded)           wer requirement         400, 115, 220, 230, 240 V 50.00 Hz           se consumption         300VA	Stray light		1.5 nm	
Wavelength setting         ±0.3 nm (858.1nm, 488.0nm)           repeatability         ±0.1 nm           Photometric accuracy         ±0.102 Abs (0 to 0.5 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (0.5 to 1.0 Abs)         ±0.002 Abs (0.5 to 1.0 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0.5 to 1.0 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0.5 to 1.0 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.100.200, 400, 800, 1200, 2400, 3800 nm/min           Response         £9.0005 Abs (200 to 860 nm)           Baseline stability (Dirit)         0.00015 Abs (200 to 860 nm)           Light source         ±0.00015 Abs (500 nm)           Light source switching         ¥0.00015 Abs (500 nm)           Light source switching         Wi lamp. D <sub>2</sub> lamp           Detector         Silicon photocide           Display         Color LCD with back-sight (10.4 inch)	Wavelength setting         ±0.3 nm (658.1nm, 488.0nm)           repeatability         ±0.1 nm           Photometric acouracy         ±0.002 Abs (0 to 0.5 Abs) ±0.006 Abs (1.0 to 2.0 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs) ±0.006 Abs (1.1 to 2.0 Abs)           Photometric repeatability         ±0.001 Abs (0 to 0.5 Abs) ±0.006 Abs (1.0 to 2.0 Abs)           (with NIST SRM 930 filter)         ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (1.0 to 2.0 Abs)           Baseline stability (Drift)         ±0.003 Abs/thr (500 nm, 2 hours after power on)           Baseline stability (Drift)         0.0003 Abs/thr (500 nm, 2 hours after power on)           Noise level         ¥0.0001 Abs (200 to 800 nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Automatic (user selectable from 325 to 370nm)           tight source switching         Automatic (user selectable from 325 to 370nm)           tight source switching         Automatic (user selectable from 325 to 370nm)           tight source switching         Automatic (user selectable from 326 to 370nm)           tight source switching         Automatic (user selectable from 326 to 370nm)           tight Approx. 31 kg         Color LCD with back-light (10.4 inch)           tight Approx. 31 kg         Color LCD with back-light (10.4 inch)           tight         Approx. 31 kg           tight <t< td=""><td>Wavelength accurac</td><td></td><td>Within 0.05% (220nm Nat. 240</td><td></td></t<>	Wavelength accurac		Within 0.05% (220nm Nat. 240	
repeatability         ±0.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.003 Abs (0.5 to 1.0 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.003 Abs (1.0 to 2.0 Abs)           Photometric repeatability (with NIST SRM 030 filter)         ±0.001 Abs (0 to 0.5 Abs) ±0.003 Abs (1.0 to 2.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         ±0.002 Abs (0.5 to 1.0 Abs) ±0.003 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/mini           Baseline stability (Drift)         0.00015 Abs (200 to 800 nm)           Noise level         ±0.00016 Abs (200 to 800 nm)           Light source         ±0.00016 Abs (500 nm)           Light source         Wi lamp, D <sub>1</sub> lamp           Light source         Silicon photocidide rotocidide           Prist UP         Silicon photocidide           Prist UF         Color LCD with back-sight (10.4 inch)	repeatability         20.1 nm           Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs)           (with NIST SRM 830 filter)         ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs)           Photometric repeatability         ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs)           (with NIST SRM 830 filter)         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3800 nm/min           Baseline stability (Dmtf)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         ±0.0001 Abs (000 to 800 nm)           Light source         ±0.0001 Abs (200 to 800 nm)           Uight source         ±0.0001 Abs (200 to 800 nm)           Variation curve         ±0.0001 Abs (200 to 800 nm)           Uight source         ±0.0001 Abs (200 to 800 nm)           Vight sou	Wavelength setting		±0.3 nm (656.1nm, 488 nm)	e)
Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.006 Abs (1.0 to 2.0 Abs)           Photometric repeatability (with NIST SRM 930 filter)         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.004 Abs (0.5 to 1.0 Abs) ±0.004 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10, 100, 200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Baseline stability (Drift)         ±0.0001 Abs (200 to 860 nm)           Noise level         ±0.00015 Abs (600 nm)           Light source         Williamp. D; lamp           Light source         Silicon photocolide           Distical y         Color LCD with back-sight (10.4 inch)	Photometric accuracy         ±0.002 Abs (0 to 0.5 Abs)           (with NIST SRM 830 filter)         ±0.002 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 2.0 Abs)         ±0.003 Abs (1.5 to 2.0 Abs)           Photometric repeatability         ±0.001 Abs (0 to 0.5 Abs)           (with NIST SRM 830 filter)         ±0.001 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (1.0 to 2.0 Abs (1.5 to 1.0 Abs)         ±0.002 Abs (1.5 to 1.0 Abs)           ±0.002 Abs (2.00 to 6.00 mm)         ±0.002 Abs (1.0 to 1.0 Abs (1.5 to 1.0 Abs)           Baseline stability (Drift)         0.0003 Abs/m (500 mm)           Baseline stability (Drift)         ±0.00015 Abs (200 to 6.00 m)           Light source switching         Automatic (user selectable from 325 to 370m)           Light source switching         Automatic (user selectable from 325 to 370m)           tisplay         C	repeatability	-	±0.1 nm	
(with NIST SRM 930 fiter)         20.002 Abs (0 to 0.5 Abs) ±0.008 Abs (0.5 to 1.0 Abs) ±0.008 Abs (0.5 to 1.0 Abs) ±0.008 Abs (1.0 to 2.0 Abs)           Photometric repeatability (with NIST SRM 930 fiter)         ±0.001 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs           Wavelength scan speed 10, 100, 200, 400, 800, 1200, 2400, 3600 nm/min Baseline stability (Drift)         0.0003 Abs/fit (500 nm, 2 hours after power on) Baseline flatness ±0.0005 Abs (200 to 860 nm)           Noise level         ±0.00015 Abs (500 hm)           Light source Williamp, D <sub>2</sub> lamp         2 lamp           Detector         Silicon photodiode           Display         Color LCD with back-light (10.4 inch)	(with NIST SRM 030 fiter)         150.002 Abs (0 50 0.5 Abs) ±0.008 Abs (1.0 to 2.0 Abs) ±0.008 Abs (1.0 to 2.0 Abs) ±0.008 Abs (1.0 to 2.0 Abs) ±0.003 Abs (1.0 to 2.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs) ±0.002 Abs (1.0 to 2.0 Abs) ±0.004 Abs (2.0 to 2.0 Abs) Baseline stability (Drift)           Baseline stability (Drift)         0.003 Abs/hr (500 nm, 2 hours after power on) Abs (2.0 to 3.0 Abs/hr (500 nm) Baseline stability (Drift)           Baseline stability (Drift)         0.0000 Abs (200 to 800 nm) ±0.0001 F Abs (500 nm) Abs (2.0 to 1.0 Dwift) back-light (10.4 inch) risplay           Color LCD wifth back-light (10.4 inch) rist UF         Color LCD wifth back-light (10.4 inch) **           se         500(W) × 005(D) × 283(H) (LCD folded) **           we requirement re consumption         300VA	Photometric accuracy	$\rightarrow$		
Baseline stability (Dirit)         0.000 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.100.200, 400, 800, 1200, 2400, 3600 nm/min           Baseline stability (Dirit)         0.0003 Abs (0.500 nm, 2 hours after power on)           Baseline stability (Dirit)         0.0003 Abs (0.500 nm, 2 hours after power on)           Light source         ±0.00015 Abs (500 nm)           Light source switching         Williamp. D <sub>2</sub> lamp           Detector         Silicon photocidode           Display         Color LCD with back-sight (10.4 inch)	±10.0g Abs (0.5 to 1.0 Abs)           ±10.0g Abs (0.5 to 1.0 Abs)           ±33% T           20.3% T           Photometric repeatability           (wth NIST SRM 030 fitter)           ±0.002 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (0.5 to 1.0 Abs)           ±0.002 Abs (0.5 to 1.0 Abs)           ±0.004 Abs (1.0 to 2.0 Abs)           ±0.003 Abs/m (500 nn. 2 hours after power on)           Baseline flateness           ±0.00015 Abs (600 nn)           Light source         W1 lamp. D; lamp           D; lamp         D; lamp           Petertor         Silicon photodiode           tisplay         Color LCD with back-light (10.4 inch)           trial UF         Centronics           sight         Approx. 31 kg           S00(W) × 605(D) × 283(H) (LCD folded) <td>(with NIST SRM 930 f</td> <td>iter)</td> <td>0.002 Abs (0 to 0.5 Abs)</td> <td></td>	(with NIST SRM 930 f	iter)	0.002 Abs (0 to 0.5 Abs)	
20.3%T         Close 30.20 Abs)           Photometric repeatability         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/minin           Response         Fast. Medium, Slow           Baseline stability (Drift)         0.00015 Abs (300 nm, 2 hours after power on)           Noise level         ±0.00016 Abs (200 to 860 nm)           Light source         W1 lamp. D; lamp           Light source switching         W1 lamp. D; lamp           Detector         Silicon photocidide           Print L/F         Color LCD with back-sight (10.4 inch)	Photometric repeatability         ±0.39 tr         1100 02 00 Abs           (with NIST SRM 930 fitter)         ±0.001 Abs (10 to 0.5 Abs)           ±0.002 Abs (0.5 to 1.0 Abs)         ±0.002 Abs (5.5 to 1.0 Abs)           ±0.002 Abs (1.0 to 2.0 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)           ±0.004 Abs (1.0 to 2.0 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)           ±0.004 Abs (1.0 to 2.0 Abs)         ±0.004 Abs (1.0 to 2.0 Abs)           Baseline stability (Drift)         0.0004 Abs (100 to 960 nm)           Baseline flatness         ±0.0004 Abs (200 to 960 nm)           Uight source switching         Automatic (user selectable from 325 to 370nm)           Light source switching         Color LCD with back-light (10.4 inch)           rift UF         Centronics           vir urger         Rs/00(W) × 805(D) × 283(H) (LCD folded)           ver requirement         100, 116, 220, 230, 240 V 50/80 Hz           sight         Approx. 31 kg           ver requirement         300VA		±	0.008 Abs (1.0 to 1.0 Abs)	
(with NIST SRM 030 filer)         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (1.0 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs)           Wavelength scan speed         10.1 100, 200, 400, 800, 1200, 2400, 3600 nm/min           Response         Fast, Medium, Slow           Baseline stability (Dntt)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         ±0.0006 Abs (200 to 960 nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Uight source switching         Automatic (user selectable from 326 to 370nm)           Detector         Silicon photocide           Print UF         Construction	(with NIST SRM 820 file)         ±0.001 Abs (0 to 0.5 Abs) ±0.002 Abs (0.5 to 1.0 Abs) ±0.002 Abs (0.5 to 1.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/min           Response         Fast, Medium, Slow           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         ±0.0004 Abs (200 to 860 nm)           Light source         Wi lamp, D; lamp           Vision photodiode         Wi lamp, D; lamp           Vision photodiode         Color LCD with back-light (10.4 inch)           tist UF         Centronics           wer requirement         400(W) × 805(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/d0 Hz           wer consumption         300VA	Photometric repeatabil	±	0.3%T (1.0 to 2.0 Abs)	
Wavelength scan speed         10.002 Abs (0.5 to 1.0 Abs) ±0.004 Abs (1.0 to 2.0 Abs ±0.15%T           Wavelength scan speed         10, 100, 200, 400, 800, 1200, 2400, 3600 nm/min           Response         Fast, Medium, Slow           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         ±0.0005 Abs (200 to 860 nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Light source switching         Automatic (user selectable from 326 to 370nm)           Display         Color LCD with back-light (10.4 inch)	bit Notes         20.002 Abs (0.5 to 1.0 Abs) 20.004 Abs (1.10 to 2.0 Abs) 20.004 Abs (1.10 to 2.0 Abs)           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3800 m/min Response           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Baseline stability (Drift)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Ught source         20.0004 Abs (200 to 060 nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Vector         Silicon photodiode           Vista level         20.00016 Abs (200 to 060 nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Netse level         20.00016 Abs (200 to 060 nm)           Vista source         Wi lamp, D <sub>2</sub> lamp           Sector         Silicon photodiode           rint U/F         Centronics           se         500(W) × 005(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           wer consumption         300VA	(with NIST SRM 930 fit		.001 Abs (0 to 0.5 Abs)	
20.1967         20.1967           Wavelength scan speed         10.100, 200, 400, 800, 1200, 2400, 3600 nm/min           Response         Fast, Medium, Slow           Baseline stability (Drift)         0.0003 Abs/f (600 nm, 2 hours after power on)           Baseline flatness         ±0.00016 Abs (200 to 860 nm)           Light source         ±0.00016 Abs (500 nm)           Light source switching         Wi lamp, D <sub>2</sub> lamp           Detector         Silicon photodiode           Display         Color LCD with back-light (10.4 inch)	Wavelength scan speed         10. 195 at (1.0 to 2.0 Abs           Response         Fast. Medium, Slow           Baseline stability (Dnit)         0.0003 Abs/hr (500 nm; 2 hours after power on)           Baseline fatness         ±0.0001 A Abs (500 nm; 2 hours after power on)           Noise level         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         ±0.0001 F Abs (500 nm; 2 hours after power on)           Vight source         Will amp, D; lamp           Vight source         Silicon photodiode           vial UF         Centronics           Vial UF         Centronics           vial UF         R5-2332 (Only for UV Solutions)           vial UF         R5-2332 (Only 6 N2(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           ver consumption         300VA		±0	002 Abs (0.5 to 1.0 Abs)	
Baseline statistic         Fast. Medium. Silow           Response         Fast. Medium. Silow           Baseline stability (Dritt)         0.0003 Abs/fit (600 nm, 2 hours after power on)           Baseline flatness         ±0.0006 Abs (200 to 860 nm)           Noise level         ±0.00015 Abs (600 nm)           Light source         Wi lamp. D <sub>2</sub> lamp           Light source switching         Automatic (user selectable from 325 to 370 nm)           Detector         Silicon photocidide           Print U/F         Color LCD with back-light (10.4 inch)	Response         10, 100, 200, 400, 800, 1200, 2400, 3000 m/min           Baseline stability (Dnft)         0.0003 Abs/hr (500 nm, 2 hours after power on)           Baseline flatness         ±0.0004 Abs (200 to 860 nm)           Uph source         ±0.0001 5 Abs (200 to 860 nm)           Ught source         ±0.0001 5 Abs (200 to 860 nm)           Ught source         Wi lamp, D <sub>2</sub> lamp           Visis level         ±0.0001 5 Abs (200 to 860 nm)           Ught source switching         Automatic (user selectable from 325 to 370nm)           Visiolary         Color LCD with back-light (10.4 inch)           rit UF         Centronics           erid S00(W) × 005(D) × 283(H) (LCD folded)           ver requirement         100, 116, 220, 230, 240 V 50/80 Hz           er consumption         300VA	Wavelength soon	±0.	1%T	
Baseline stability (Drift)     Fast, Medium, Slow       Baseline stability (Drift)     D.0003 Abs/hr (500 nm, 2 hours after power on)       Baseline flatness     ±0.0006 Abs (200 to 960 nm)       Voise level     ±0.0006 Abs (200 to 960 nm)       Light source     Wi lamp, D <sub>1</sub> lamp       Light source switching     Automatic (user selectable from 326 to 370nm)       Display     Color LCD with back-light (10.4 inch)	Baseline stability (Drift)         Fast, Medium, Slow         2400, 3600 nm/min           Baseline stability (Drift)         0.003 Abs/hr (500 nm, 2 hours after power on)         Baseline flatness         ±0.0006 Abs (200 to 660 nm)           Uph source         ±0.0007 Abs/hr (500 nm, 2 hours after power on)         Baseline flatness         ±0.0007 baseline (500 nm)           Uph source         ±0.0007 base (500 nm)         ±0.0017 baseline (user selectable from 325 to 370nm)         Baseline flatness           Uph source switching         Automatic (user selectable from 325 to 370nm)         Silicon photodiode         Silicon photodiode           Visualy         Color LCD with back-light (10.4 inch)         Eest         Silicon photodiode           set 500(W) × 605(D) × 283(H) (LCD folded)         Eest         Silicol (M) × 605(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz         Eest           er consumption         300V/A         300V/A	Response	10,	100, 200, 400, 800, 1011	
Baseline flatness         ±0.0003 Abs/hr (500 nm, 2 hours after power on)           Noise level         ±0.0006 Abs (200 to 960 nm)           Light source         ±0.00015 Abs (500nm)           Light source switching         Automatic (user selectable from 326 to 370nm)           Display         Color LCD with back-light (10.4 inch)	Baseline flatness         0.0003 Abs/thr (500 nm, 2 hours after power on)           Noise level         ±0.0006 Abs (200 to 060 nm)           Light source         ±0.0001 5 Abs (600nm)           Light source switching         Automatic (user selectable from 326 to 370nm)           Selector         Silicon photodiode           rint UF         Color LCD with back-light (10.4 inch)           rint UF         Centronics           selector         RS-232C (Only for UV Solutions)           sight         500(W) × 085(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           er consumption         300VA	Baseline stability (D)	Fas	t. Medium, Slow	/min
Noise level         ±0.0006 Abs (200 to 860 nm)           Light source         ±0.00016 Abs (500 nm)           Light source switching         Wi lamp, D <sub>2</sub> lamp           Light source switching         Automatic (user selectable from 325 to 370 nm)           Display         Color LCD with back-light (10.4 inch)	Noise level         ±0.0004 Abs (200 to 950 nm)           Light source         ±0.00015 Abs (500nm)           Light source         Wil Iamp, D <sub>2</sub> Iamp           Jource switching         Automatic (user selectable from 326 to 370nm)           Jetector         Silicon photodiode           rint U/F         Color LCD with back-light (10.4 inch)           erial U/F         Centronics           silicon (0)(0) × 803(C) × 283(H) (LCD folded)           erial U/F         R-5232C (Cnly for U/ Solutions)           erial source silicon (0) × 805(D) × 283(H) (LCD folded)           erial u/F         R-5232C (201 V 50/80 Hz           er requirement         100, 115, 220, 230, 240 V 50/80 Hz           er consumption         300VA	Baseline flatnoss	0.00	03 Abs/hr (500 pm 2 )	
Light source         ±0.00015 (bbs 600nm)           Light source         WI lamp, D <sub>2</sub> lamp           Light source switching         Automatic (user selectable from 325 to 370nm)           Detector         Silicon photodiode           Print UF         Cotor LCD with back-light (10.4 inch)	Light source         ±0.000 15 Abs (600nm)           Light source         Wi lamp, D <sub>2</sub> lamp           Jight source switching         Automatic (user selectable from 326 to 370nm)           Vetector         Silicon photodioide           risplay         Color LCD with back-light (10.4 inch)           erial UP         Centronics           sight         S00(W) × 805(D) × 283(H) (LCD folded)           wer requirement         100, 116, 220, 230, 240 V 50/80 Hz           wer consumption         300VA	Noise level	±0.0	006 Abs (200 to one	n)
United of the second	Jight source switching         WI lamp, D; lamp           Jight source switching         Automatic (user selectable from 325 to 370nm)           Vetedor         Sillcon photodiode           Visplay         Color LCD with back-light (10.4 inch)           end LIFF         Centronics           see         500(W) × 005(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           wer consumption         300V/A	Light source	±0.00	0015 Abs (600-	
Detector Silicon photodiode Display Color LCD with back-light (10.4 inch)	Detector     Automatic (user selectable from 325 to 370nm)       Selector     Silicon photodiode       rint UP     Color LCD with back-light (10.4 inch)       rint UP     Centronics       reial UP     R5-232C (Chly for UV Solutions)       sight     Approx. 31 kg       wer requirement     100, 115, 220, 230, 240 V 50/80 Hz       re consumption     300VA	Light source suit in	WI Ia	mp, D <sub>2</sub> (amp	
Display Silicon photoelocide Color LCD with back-light (10.4 inch)	Silicon photodiode           Visplay         Silicon photodiode           rint U/F         Color LCD with back-light (10.4 inch)           rint U/F         Centroids           refail U/F         Restraics           Silicon 9000000000000000000000000000000000000	Detector	Auton	natic (User color)	
Print I/F Color LCD with back-light (10.4 inch)	Int UF         Color LCD with back-light (10.4 inch)           entronics         Centronics           erial UF         RS-232C (Only for UV Solutions)           sight         500(W) × 805(D) × 283(H) (LCD folded)           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           ver consumption         300VA	Display	Silicor	photodiode	
Contract Dack-light (10.4 inch)	Interference         Centronics           end         R5-232C (Only for UV Solutions)           se         500(W) × 005(D) × 283(H) (LCD folded)           sight         Approx. 31 kg           ver requirement         100, 115, 220, 230, 240 V 50/80 Hz           300V/A         300V/A	Print I/F	Color	CD with bask 5	
Senal //F	RS-232C (Only for UV Solutions)           sight         500(W) × 805(D) × 283(H) (LCD folded)           right         Approx. 31 kg           wer requirement         100, 115, 220, 230, 240 V 50/80 Hz           ver consumption         300VA	Serial I/F	Centro	nics	
Size RS-232C (Only for LIV a	sight         500(W) × 605(0) × 283(H) (LCD folded)           wer requirement         Approx. 31 kg           100, 115, 220, 230, 240 V 50/60 Hz           ver consumption         300VA	Size	RS-232	C (Only for LIV a	
Veight 500(W) × 605(D) × 200 m	wer requirement         Approx. 31 kg           100, 115, 220, 230, 240 V 50/80 Hz           ver consumption           300VA	Weight	500(W)	× 605(D) × 200 m	
Power requirements Approx. 31 kg	100, 115, 220, 230, 240 V 50/80 Hz Per consumption 300VA	Power require	Approx.	31 kg	
Power oppsium i 100, 115, 220, 230, 240	300VA 300VA	Power consumer:	100, 115	220, 230, 240	
300VA 300VA		torisumption	300VA	11, 200, 240 V 50/60 Hz	
Power consumption 300VA		Power consumption	300VA	, 220, 230, 240 V 50/60 Hz	
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